2SD1820

Silicon NPN epitaxial planar type

For general amplification Complementary to 2SB1219

Features

- \bullet Low collector-emitter saturation voltage $V_{\mbox{CE(sat)}}$
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

Absolute Maximum Ratings $T_a = 25^{\circ}C$ Symbol Parameter Rating Unit Collector-base voltage (Emitter open) 30 V V_{CBO} Collector-emitter voltage (Base open) V VCEO 25 5 V Emitter-base voltage (Collector open) V_{EBO} Collector current 500 I_{C} mА Peak collector current I_{CP} 1 А Collector power dissipation 150 mW P_{C} Junction temperature Ti 150 °C -55 to +150 °C Storage temperature T_{stg}

Package

- Code
- SMini3-G1
- Pin Name
 - 1. Base
 - 2. Emitter
 - 3. Collector
- Marking Symbol: W

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 10 \ \mu {\rm A}, I_{\rm E} = 0$	30			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 2 {\rm mA}, I_{\rm B} = 0$	25			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 10 \ \mu A, I_{\rm C} = 0$	5			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 20 \text{ V}, I_E = 0$			0.1	μΑ
Forward current transfer ratio *1	h _{FE1} *2	$V_{CE} = 10 \text{ V}, I_C = 150 \text{ mA}$	85		340	
	h _{FE2}	$V_{CE} = 10 \text{ V}, I_C = 500 \text{ mA}$	40			
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_{\rm C} = 300 \text{ mA}, I_{\rm B} = 30 \text{ mA}$		0.35	0.60	V
Transition frequency	f _T	$V_{CB} = 10 \text{ V}, I_E = -50 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance (Common base, input open circuited)	C _{ob}	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		6	15	pF

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

*2: Rank classification

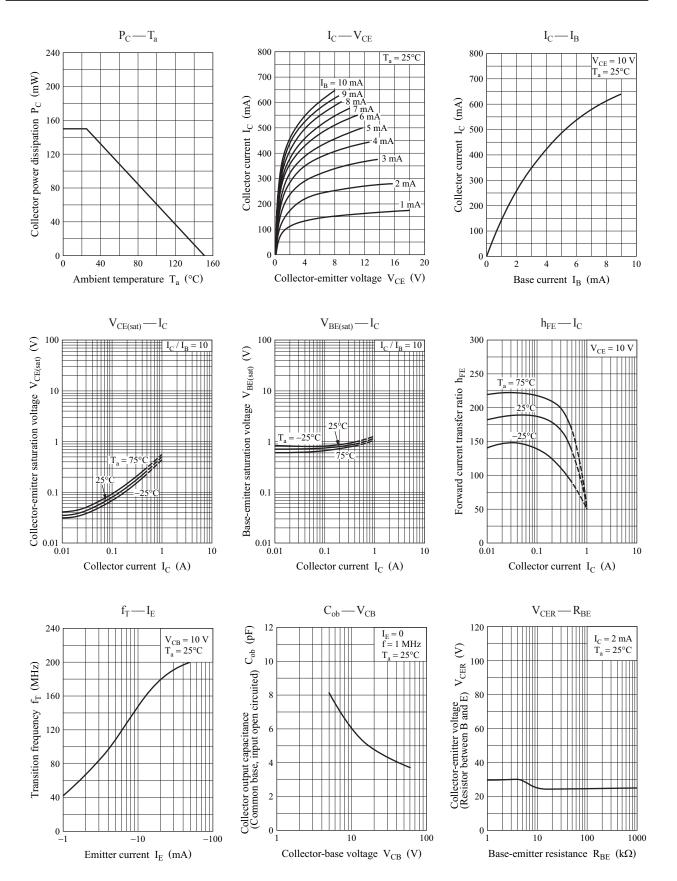
Rank	Q	R	S	No-rank
h _{FE1}	85 to 170	120 to 240	170 to 340	85 to 340
Marking symbol	WQ	WR	WS	

Product of no-rank is not classified and have no marking symbol for rank.

^{2. *1:} Pulse measurement

2SD1820

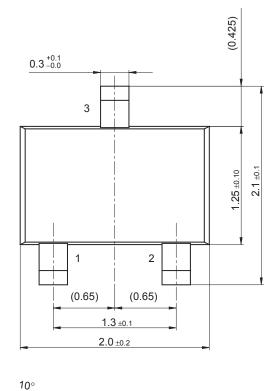
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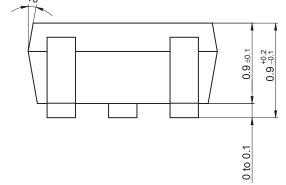


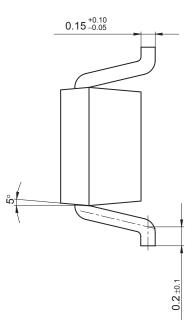
Panasonic

SMini3-G1

Unit: mm







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